High Current, Micropower Single Cell, 600kHz DC/DC Converters

FEATURES

- **5V at 1A from a Single Li-Ion Cell**
- **5V at 800mA in SEPIC Mode from Four NiCd Cells**
- **Fixed Frequency Operation: 600kHz**
- **Boost Converter Outputs up to 34V**
- Starts into Heavy Loads
- Automatic Burst Mode™ Operation at Light Load (LT1308A)
- Continuous Switching at Light Loads (LT1308B)
- Low V_{CESAT} Switch: 300mV at 2A
- Pin-for-Pin Upgrade Compatible with LT1308
- Lower Quiescent Current in Shutdown: 1µA (Max)
- Improved Accuracy Low-Battery Detector Reference: 200mV ±2%
- Available in 8-Lead SO and 14-Lead TSSOP Packages

APPLICATIONS

- GSM/CDMA Phones
- Digital Cameras
- LCD Bias Supplies
- Answer-Back Pagers
- GPS Receivers
- Battery Backup Supplies
- Handheld Computers

DESCRIPTION

The LT®1308A/LT1308B are micropower, fixed frequency step-up DC/DC converters that operate over a 1V to 10V input voltage range. They are improved versions of the LT1308 and are recommended for use in new designs. The LT1308A features automatic shifting to power saving Burst Mode operation at light loads and consumes just 140µA at no load. The LT1308B features continuous switching at light loads and operates at a quiescent current of 2.5mA. Both devices consume less than 1µA in shutdown.

Low-battery detector accuracy is significantly tighter than the LT1308. The 200mV reference is specified at ±2% at room and ±3% over temperature. The shutdown pin enables the device when it is tied to a 1V or higher source and does not need to be tied to V_{IN} as on the LT1308. An internal V_C clamp results in improved transient response and the switch voltage rating has been increased to 36V, enabling higher output voltage applications.

The LT1308A/LT1308B are available in the 8-lead SO and the 14-lead TSSOP packages.

, LT, LTC, LTM, Burst Mode, Linear Technology and the Linear logo are registered trademarks of Linear Technology Corporation. All other trademarks are the property of their respective owners.

TYPICAL APPLICATION

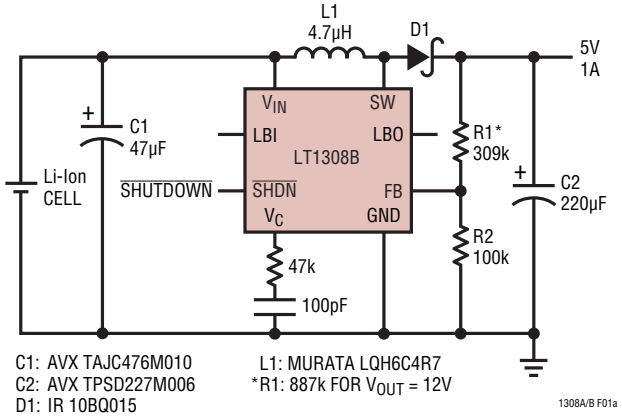
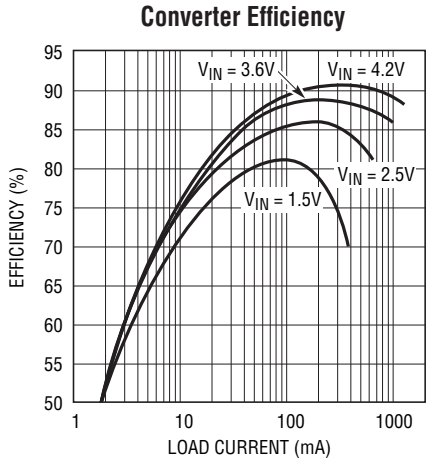


Figure 1. LT1308B Single Li-Ion Cell to 5V/1A DC/DC Converter

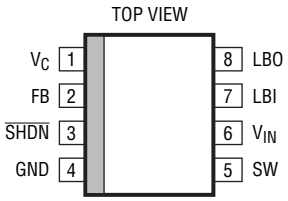


ABSOLUTE MAXIMUM RATINGS (Note 1)

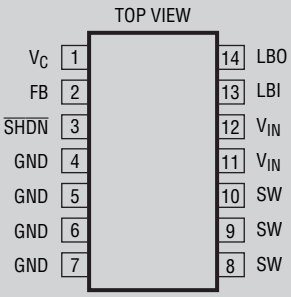
V_{IN}, $\overline{SHDN}$, LBO Voltage 10V
SW Voltage ..... –0.4V to 36V
FB Voltage ..... V_{IN} + 1V
V_C Voltage 2V
LBI Voltage ..... –0.1V to 1V
Current into FB Pin ..... ±1mA

Operating Temperature Range
Commercial ..... 0°C to 70°C
Extended Commerial (Note 2) ..... –40°C to 85°C
Industrial ..... –40°C to 85°C
Storage Temperature Range ..... –65°C to 150°C
Lead Temperature (Soldering, 10 sec) ..... 300°C

PIN CONFIGURATION



S8 PACKAGE
8-LEAD PLASTIC SO
T_{JMAX} = 125°C, θ_{JA} = 190°C/W



F PACKAGE
14-LEAD PLASTIC TSSOP
(NOTE 6)
T_{JMAX} = 125°C, θ_{JA} = 80°C/W

OBSOLETE, FOR INFORMATION PURPOSES ONLY
Contact Linear Technology for Potential Replacement

ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT1308ACS8#PBF	LT1308ACS8#TRPBF	1308A	8-Lead Plastic SO	0°C to 70°C
LT1308AIS8#PBF	LT1308AIS8#TRPBF	1308AI	8-Lead Plastic SO	–40°C to 85°C
LT1308BCS8#PBF	LT1308BCS8#TRPBF	1308B	8-Lead Plastic SO	0°C to 70°C
LT1308BIS8#PBF	LT1308BIS8#TRPBF	1308BI	8-Lead Plastic SO	–40°C to 85°C
LT1308ACF#PBF	LT1308ACF#TRPBF	LT1308ACF	14-Lead Plastic TSSOP	0°C to 70°C
LT1308BCF#PBF	LT1308BCF#TRPBF	LT1308BCF	14-Lead Plastic TSSOP	0°C to 70°C
LEAD BASED FINISH	**TAPE AND REEL**	**PART MARKING**	**PACKAGE DESCRIPTION**	**TEMPERATURE RANGE**
LT1308ACS8	LT1308ACS8#TR	1308A	8-Lead Plastic SO	0°C to 70°C
LT1308AIS8	LT1308AIS8#TR	1308AI	8-Lead Plastic SO	–40°C to 85°C
LT1308BCS8	LT1308BCS8#TR	1308B	8-Lead Plastic SO	0°C to 70°C
LT1308BIS8	LT1308BIS8#TR	1308BI	8-Lead Plastic SO	–40°C to 85°C
LT1308ACF	LT1308ACF#TR	LT1308ACF	14-Lead Plastic TSSOP	0°C to 70°C
LT1308BCF	LT1308BCF#TR	LT1308BCF	14-Lead Plastic TSSOP	0°C to 70°C

Consult LTC Marketing for parts specified with wider operating temperature ranges.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/
This product is only offered in trays. For more information go to: http://www.linear.com/packaging/

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. Commercial Grade 0°C to 70°C. V_{IN} = 1.1V, $V_{\overline{SHDN}}$ = V_{IN}, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I_Q	Quiescent Current	Not Switching, LT1308A Switching, LT1308B $V_{\overline{SHDN}}$ = 0V (LT1308A/LT1308B)			140 2.5 0.01	240 4 1	µA mA µA
V_{FB}	Feedback Voltage		●	1.20	1.22	1.24	V
I_B	FB Pin Bias Current	(Note 3)	●		27	80	nA
	Reference Line Regulation	1.1V ≤ V_{IN} ≤ 2V 2V ≤ V_{IN} ≤ 10V	● 		0.03 0.01	0.4 0.2	%/V %/V
	Minimum Input Voltage				0.92	1	V
g_m	Error Amp Transconductance	ΔI = 5µA			60		µmhos
A_V	Error Amp Voltage Gain				100		V/V
f_{OSC}	Switching Frequency	V_{IN} = 1.2V	●	500	600	700	kHz
	Maximum Duty Cycle		●	82	90		%
	Switch Current Limit	Duty Cycle = 30% (Note 4)		2	3	4.5	A
	Switch V_{CESAT}	I_{SW} = 2A (25°C, 0°C), V_{IN} = 1.5V I_{SW} = 2A (70°C), V_{IN} = 1.5V			290 330	350 400	mV mV
	Burst Mode Operation Switch Current Limit (LT1308A)	V_{IN} = 2.5V, Circuit of Figure 1			400		mA
	Shutdown Pin Current	$V_{\overline{SHDN}}$ = 1.1V $V_{\overline{SHDN}}$ = 6V $V_{\overline{SHDN}}$ = 0V	● ● ●		2 20 0.01	5 35 0.1	µA µA µA
	LBI Threshold Voltage		 ●	196 194	200 200	204 206	mV mV
	LBO Output Low	I_{SINK} = 50µA	●		0.1	0.25	V
	LBO Leakage Current	V_{LBI} = 250mV, V_{LBO} = 5V	●		0.01	0.1	µA
	LBI Input Bias Current (Note 5)	V_{LBI} = 150mV			33	100	nA
	Low-Battery Detector Gain				3000		V/V
	Switch Leakage Current	V_{SW} = 5V	●		0.01	10	µA

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. Industrial Grade –40°C to 85°C. V_{IN} = 1.2V, $V_{\overline{SHDN}}$ = V_{IN}, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I_Q	Quiescent Current	Not Switching, LT1308A Switching, LT1308B $V_{\overline{SHDN}}$ = 0V (LT1308A/LT1308B)	● ● ●		140 2.5 0.01	240 4 1	µA mA µA
V_{FB}	Feedback Voltage		●	1.19	1.22	1.25	V
I_B	FB Pin Bias Current	(Note 3)	●		27	80	nA
	Reference Line Regulation	1.1V ≤ V_{IN} ≤ 2V 2V ≤ V_{IN} ≤ 10V	● ●		0.05 0.01	0.4 0.2	%/V %/V
	Minimum Input Voltage				0.92	1	V
g_m	Error Amp Transconductance	ΔI = 5µA			60		µmhos
A_V	Error Amp Voltage Gain				100		V/V

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. Industrial Grade –40°C to 85°C. V_{IN} = 1.2V, $V_{\overline{SHDN}}$ = V_{IN}, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
f_{OSC}	Switching Frequency		●	500	600	750	kHz
	Maximum Duty Cycle		●	82	90		%
	Switch Current Limit	Duty Cycle = 30% (Note 4)		2	3	4.5	A
	Switch V_{CESAT}	I_{SW} = 2A (25°C, –40°C), V_{IN} = 1.5V I_{SW} = 2A (85°C), V_{IN} = 1.5V			290 330	350 400	mV mV
	Burst Mode Operation Switch Current Limit (LT1308A)	V_{IN} = 2.5V, Circuit of Figure 1			400		mA
	Shutdown Pin Current	$V_{\overline{SHDN}}$ = 1.1V $V_{\overline{SHDN}}$ = 6V $V_{\overline{SHDN}}$ = 0V	● ●		2 20 0.01	5 35 0.1	µA µA µA
	LBI Threshold Voltage		 ●	196 193	200 200	204 207	mV mV
	LBO Output Low	I_{SINK} = 50µA	●		0.1	0.25	V
	LBO Leakage Current	V_{LBI} = 250mV, V_{LBO} = 5V	●		0.01	0.1	µA
	LBI Input Bias Current (Note 5)	V_{LBI} = 150mV			33	100	nA
	Low-Battery Detector Gain				3000		V/V
	Switch Leakage Current	V_{SW} = 5V	●		0.01	10	µA

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LT1308ACS8, LT1308ACF, LT1308BCS8 and LT1308BCF are designed, characterized and expected to meet the industrial temperature limits, but are not tested at –40°C and 85°C. I grade devices are guaranteed over the –40°C to 85°C operating temperature range.

Note 3: Bias current flows into FB pin.

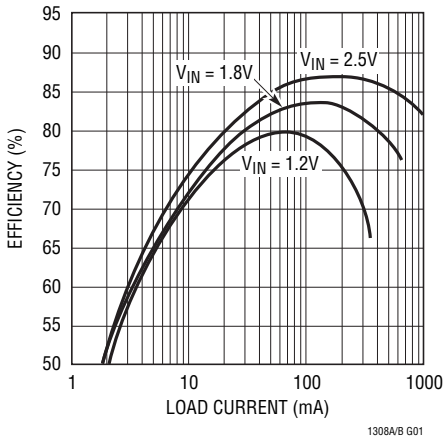
Note 4: Switch current limit guaranteed by design and/or correlation to static tests. Duty cycle affects current limit due to ramp generator (see Block Diagram).

Note 5: Bias current flows out of LBI pin.

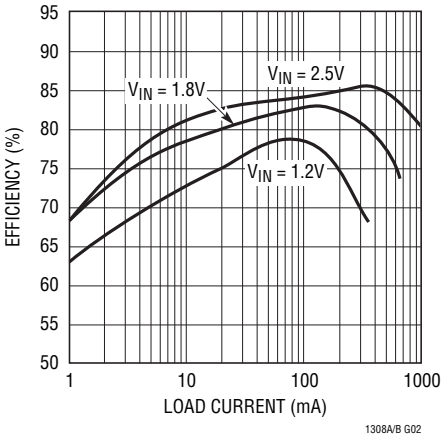
Note 6: Connect the four GND pins (Pins 4–7) together at the device. Similarly, connect the three SW pins (Pins 8–10) together and the two V_{IN} pins (Pins 11, 12) together at the device.

TYPICAL PERFORMANCE CHARACTERISTICS

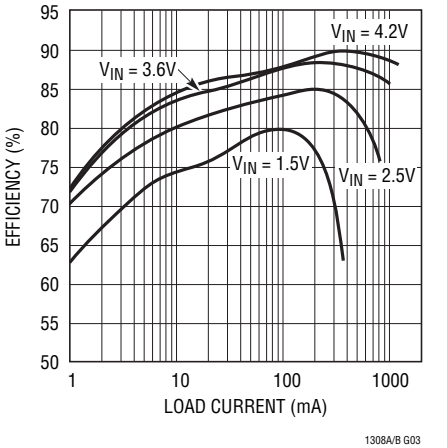
LT1308B
3.3V Output Efficiency



LT1308A
3.3V Output Efficiency

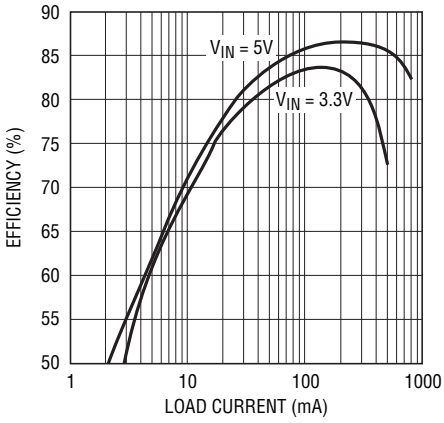


LT1308A
5V Output Efficiency



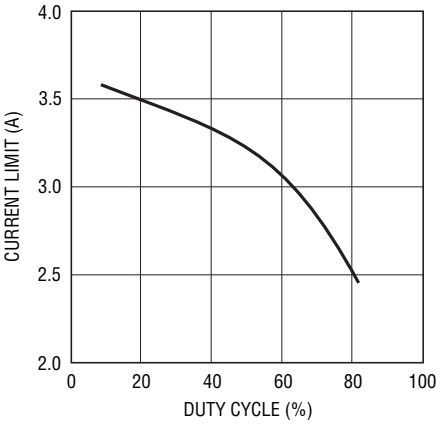
TYPICAL PERFORMANCE CHARACTERISTICS

LT1308B
12V Output Efficiency



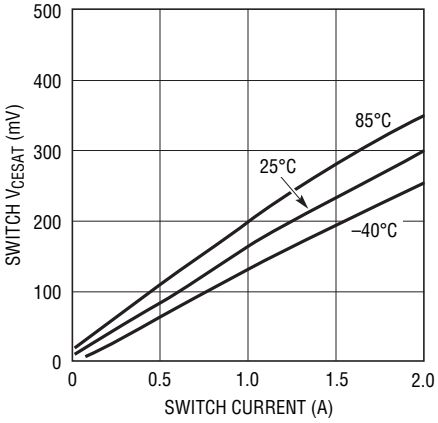
1308A/B G04

Switch Current Limit vs Duty Cycle



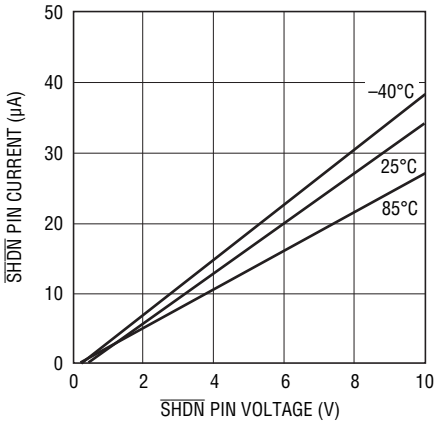
1308 • G05

Switch Saturation Voltage vs Current



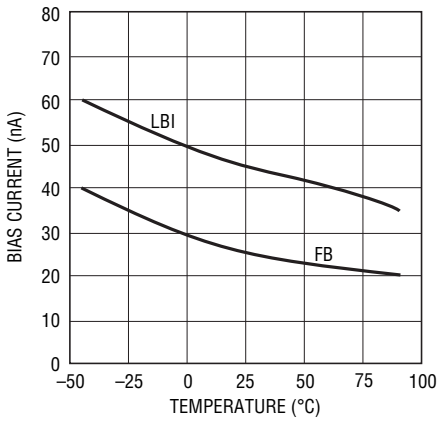
1308 G06

SHDN Pin Bias Current vs Voltage



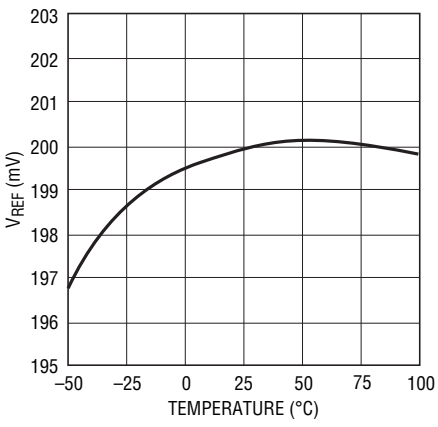
1308 G07

FB, LBI Bias Current vs Temperature



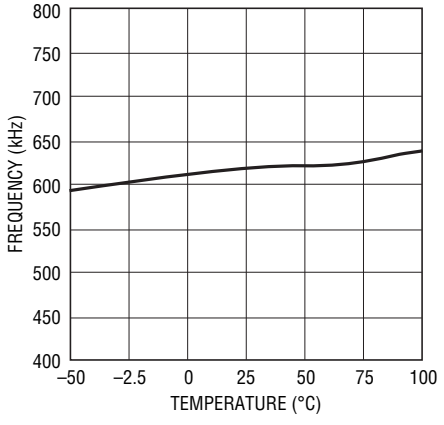
1308 • G08

Low Battery Detector Reference vs Temperature



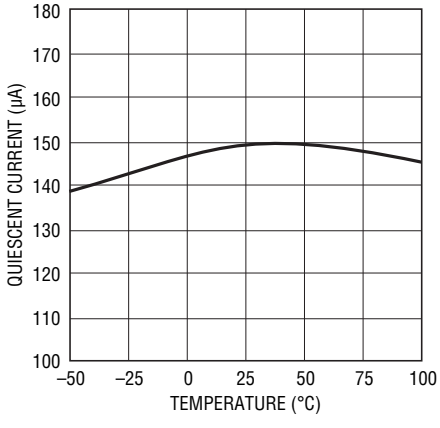
1308 • G09

Oscillator Frequency vs Temperature



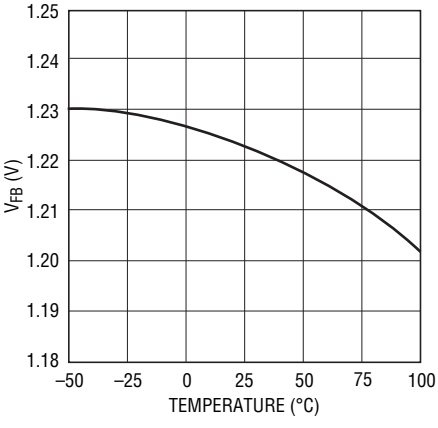
1308 • G10

LT1308A Quiescent Current vs Temperature



1308 • G11

Feedback Pin Voltage vs Temperature



1308 • G12

PIN FUNCTIONS (SO/TSSOP)

V_C (Pin 1/Pin 1): Compensation Pin for Error Amplifier. Connect a series RC from this pin to ground. Typical values are 47kΩ and 100pF. Minimize trace area at V_C.

FB (Pin 2/Pin 2): Feedback Pin. Reference voltage is 1.22V. Connect resistive divider tap here. Minimize trace area at FB. Set V_{OUT} according to:

$V_{OUT} = 1.22V(1 + R1/R2)$.

$\overline{SHDN}$ (Pin 3/Pin 3): Shutdown. Ground this pin to turn off switcher. To enable, tie to 1V or more. $\overline{SHDN}$ does not need to be at V_{IN} to enable the device.

GND (Pin 4/Pins 4, 5, 6, 7): Ground. Connect directly to local ground plane. Ground plane should enclose all components associated with the LT1308. PCB copper connected to these pins also functions as a heat sink. For the TSSOP package, connect all pins to ground copper to get the best heat transfer. This keeps chip heating to a minimum.

SW (Pin 5/Pins 8, 9, 10): Switch Pins. Connect inductor/diode here. Minimize trace area at these pins to keep EMI down. For the TSSOP package, connect all SW pins together at the package.

V_{IN} (Pin 6/Pins 11, 12): Supply Pins. Must have local bypass capacitor right at the pins, connected directly to ground. For the TSSOP package, connect both V_{IN} pins together at the package.

LBI (Pin 7/Pin 13): Low-Battery Detector Input. 200mV reference. Voltage on LBI must stay between –100mV and 1V. Low-battery detector does not function with $\overline{SHDN}$ pin grounded. Float LBI pin if not used.

LBO (Pin 8/Pin 14): Low-Battery Detector Output. Open collector, can sink 50µA. A 220kΩ pull-up is recommended. LBO is high impedance when $\overline{SHDN}$ is grounded.

BLOCK DIAGRAMS

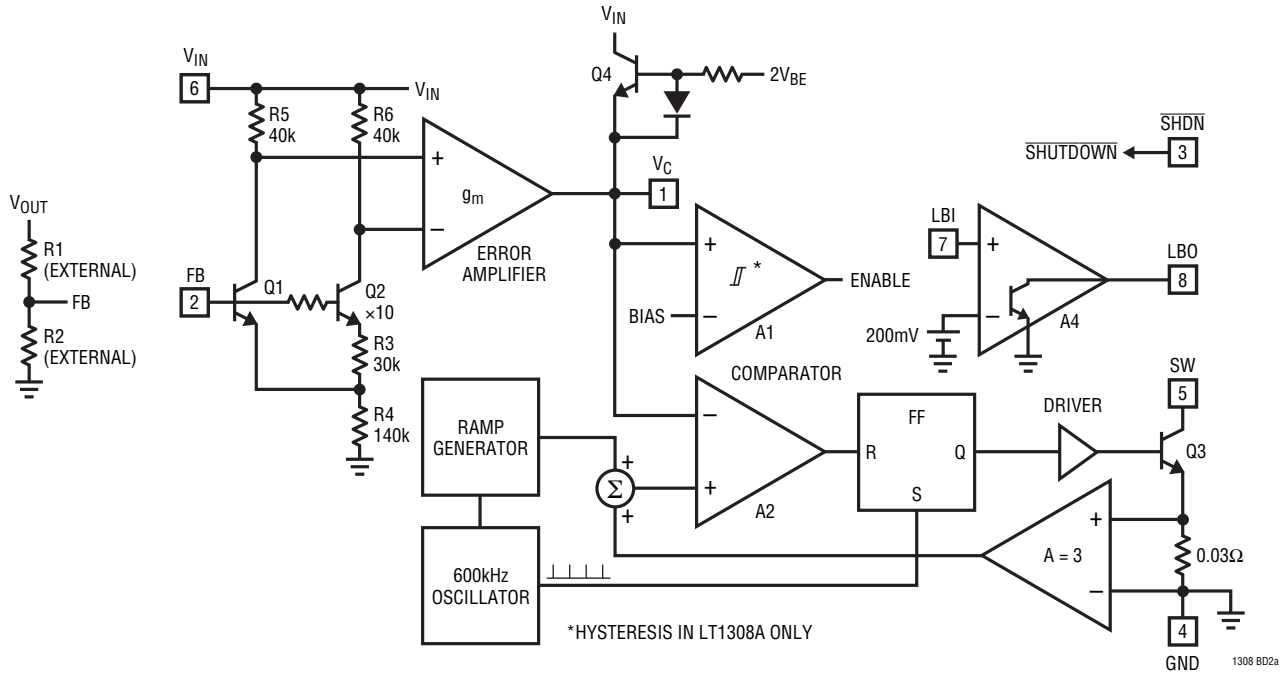


Figure 2a. LT1308A/LT1308B Block Diagram (SO-8 Package)

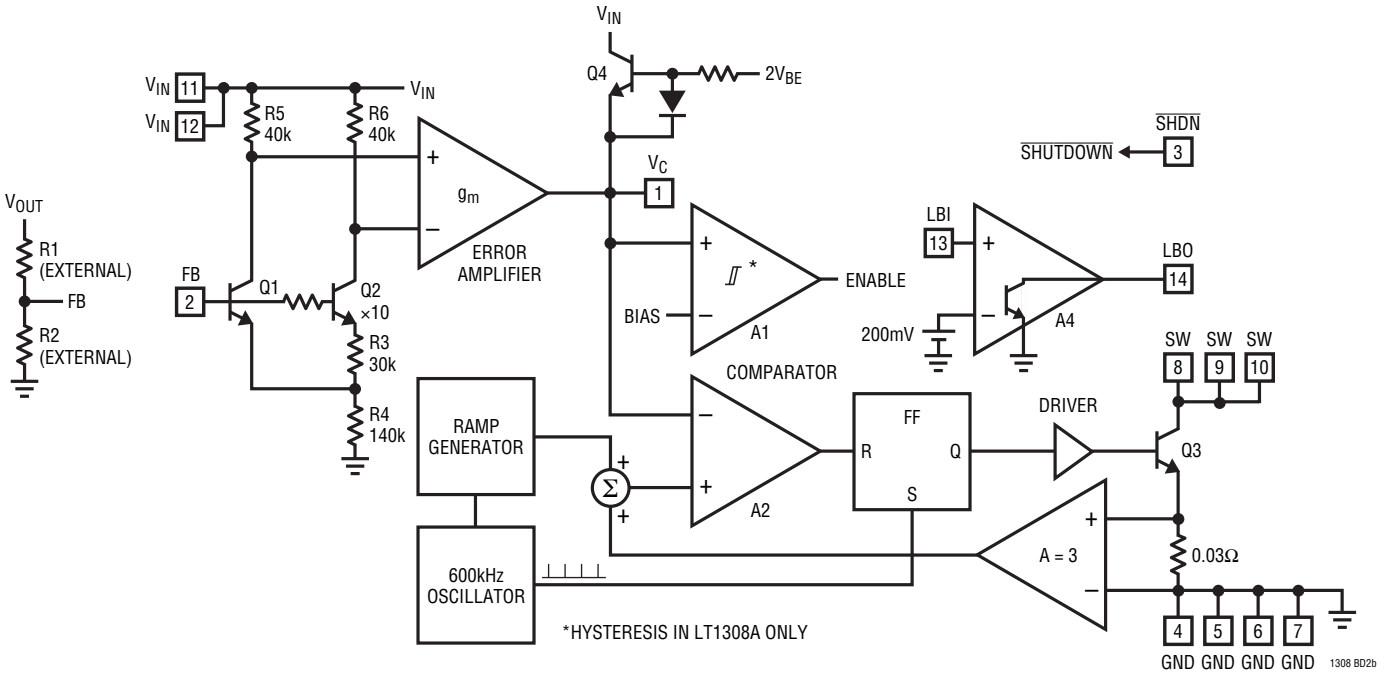


Figure 2b. LT1308A/LT1308B Block Diagram (TSSOP Package)

APPLICATIONS INFORMATION

OPERATION

The LT1308A combines a current mode, fixed frequency PWM architecture with Burst Mode micropower operation to maintain high efficiency at light loads. Operation can be best understood by referring to the block diagram in Figure 2. Q1 and Q2 form a bandgap reference core whose loop is closed around the output of the converter. When V_{IN} is 1V, the feedback voltage of 1.22V, along with an 80mV drop across R5 and R6, forward biases Q1 and Q2's base collector junctions to 300mV. Because this is not enough to saturate either transistor, FB can be at a higher voltage than V_{IN}. When there is no load, FB rises slightly above 1.22V, causing V_C (the error amplifier's output) to decrease. When V_C reaches the bias voltage on hysteretic comparator A1, A1's output goes low, turning off all circuitry except the input stage, error amplifier and low-battery detector. Total current consumption in this state is 140µA. As output loading causes the FB voltage to decrease, A1's output goes high, enabling the rest of the IC. Switch current is limited to approximately 400mA initially after A1's output goes high. If the load is light, the output voltage (and FB voltage) will increase until A1's output goes low, turning off the rest of the LT1308A. Low frequency ripple voltage appears at the output. The ripple frequency is dependent on load current and output capacitance. This Burst Mode operation keeps the output regulated and reduces average current into the IC, resulting in high efficiency even at load currents of 1mA or less.

If the output load increases sufficiently, A1's output remains high, resulting in continuous operation. When the LT1308A is running continuously, peak switch current is controlled by V_C to regulate the output voltage. The switch is turned on at the beginning of each switch cycle. When the summation of a signal representing switch current and a ramp generator (introduced to avoid subharmonic oscillations at duty factors greater than 50%) exceeds the V_C signal, comparator A2 changes state, resetting the flip-flop and turning off the switch. Output voltage increases as switch current is increased. The output, attenuated by a resistor divider, appears at the FB pin, closing the overall loop. Frequency compensation is provided by an external series RC network connected between the V_C pin and ground.

Low-battery detector A4's open-collector output (LBO) pulls low when the LBI pin voltage drops below 200mV. There is no hysteresis in A4, allowing it to be used as an amplifier in some applications. The entire device is disabled when the $\overline{SHDN}$ pin is brought low. To enable the converter, $\overline{SHDN}$ must be at 1V or greater. It need not be tied to V_{IN} as on the LT1308.

The LT1308B differs from the LT1308A in that there is no hysteresis in comparator A1. Also, the bias point on A1 is set lower than on the LT1308B so that switching can occur at inductor current less than 100mA. Because A1 has no hysteresis, there is no Burst Mode operation at light loads and the device continues switching at constant frequency. This results in the absence of low frequency output voltage ripple at the expense of efficiency.

The difference between the two devices is clearly illustrated in Figure 3. The top two traces in Figure 3 shows an LT1308A/LT1308B circuit, using the components indicated in Figure 1, set to a 5V output. Input voltage is 3V. Load current is stepped from 50mA to 800mA for both circuits. Low frequency Burst Mode operation voltage ripple is observed on Trace A, while none is observed on Trace B.

At light loads, the LT1308B will begin to skip alternate cycles. The load point at which this occurs can be decreased by increasing the inductor value. However, output ripple will continue to be significantly less than the LT1308A output ripple. Further, the LT1308B can be forced into micropower mode, where I_Q falls from 3mA to 200µA by sinking 40µA or more out of the V_C pin. This stops switching by causing A1's output to go low.

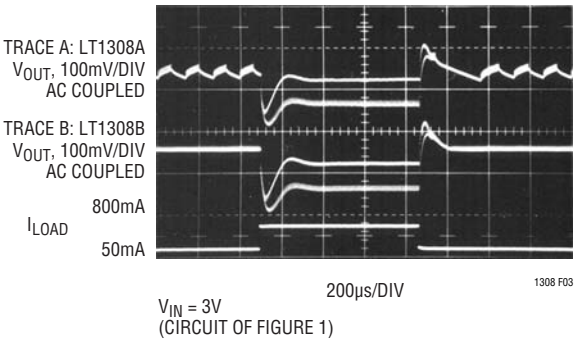


Figure 3. LT1308A Exhibits Burst Mode Operation Output Voltage Ripple at 50mA Load, LT1308B Does Not

APPLICATIONS INFORMATION

Waveforms for a LT1308B 5V to 12V boost converter using a 10µF ceramic output capacitor are pictured in Figures 4 and 5. In Figure 4, the converter is operating in continuous mode, delivering a load current of approximately 500mA. The top trace is the output. The voltage increases as inductor current is dumped into the output capacitor during the switch off time, and the voltage decreases when the switch is on. Ripple voltage is in this case due to capacitance, as the ceramic capacitor has little ESR. The middle trace is the switch voltage. This voltage alternates between a V_{CESAT} and V_{OUT} plus the diode drop. The lower trace is the switch current. At the beginning of the switch cycle, the current is 1.2A. At the end of the switch on time, the current has increased to 2A, at which point the switch turns off and the inductor current flows into the output capacitor through the diode. Figure 5 depicts converter waveforms at a light load. Here the converter operates in discontinuous mode. The inductor current reaches zero during the switch off time, resulting in some ringing at the switch node. The ring frequency is set by switch capacitance, diode capacitance and inductance. This ringing has little energy, and its sinusoidal shape suggests it is free from harmonics. Minimizing the copper area at the switch node will prevent this from causing interference problems.

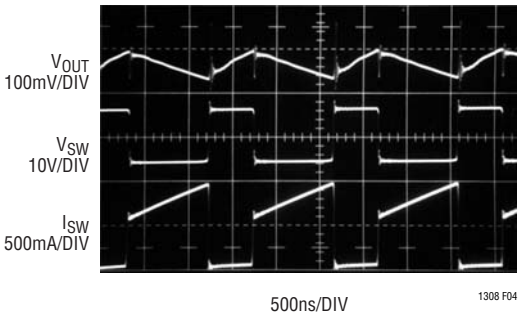


Figure 4. 5V to 12V Boost Converter Waveforms in Continuous Mode. 10µF Ceramic Capacitor Used at Output

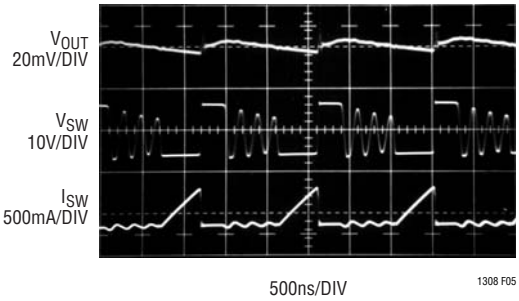


Figure 5. Converter Waveforms in Discontinuous Mode

LAYOUT HINTS

The LT1308A/LT1308B switch current at high speed, mandating careful attention to layout for proper performance. *You will not get advertised performance with careless layout.* Figure 6 shows recommended component placement for an SO-8 package boost (step-up) converter. Follow this closely in your PC layout. Note the direct path of the switching loops. Input capacitor C1 *must* be placed close (<5mm) to the IC package. As little as 10mm of wire or PC trace from C_{IN} to V_{IN} will cause problems such as inability to regulate or oscillation.

The negative terminal of output capacitor C2 should tie close to the ground pin(s) of the LT1308A/LT1308B. Doing this reduces dI/dt in the ground copper which keeps high frequency spikes to a minimum. The DC/DC converter ground should tie to the PC board ground plane at one place only, to avoid introducing dI/dt in the ground plane.

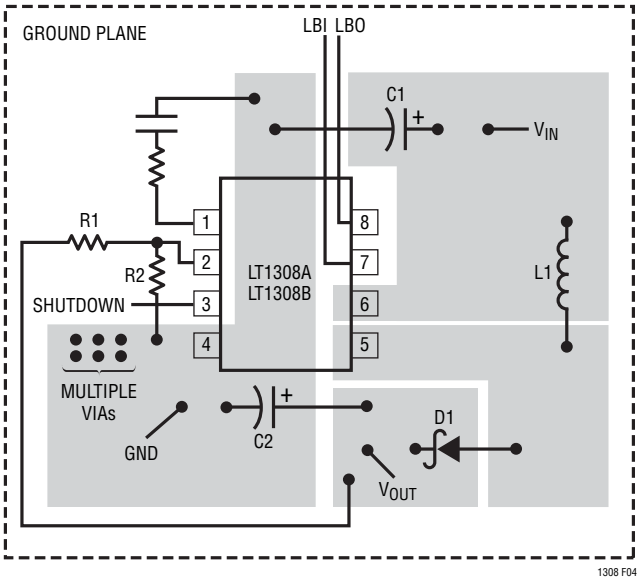


Figure 6. Recommended Component Placement for SO-8 Package Boost Converter. Note Direct High Current Paths Using Wide PC Traces. Minimize Trace Area at Pin 1 (V_C) and Pin 2 (FB). Use Multiple Vias to Tie Pin 4 Copper to Ground Plane. Use Vias at One Location Only to Avoid Introducing Switching Currents into the Ground Plane

Figure 7 shows recommended component placement for a boost converter using the TSSOP package. Placement is similar to the SO-8 package layout.

APPLICATIONS INFORMATION

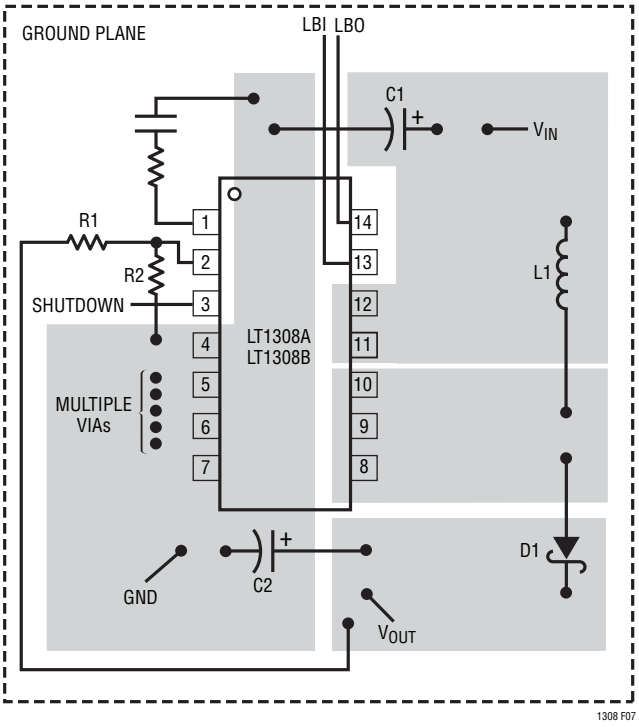


Figure 7. Recommended Component Placement for TSSOP Boost Converter. Placement is Similar to Figure 4

A SEPIC (Single-Ended Primary Inductance Converter) schematic is shown in Figure 8. This converter topology produces a regulated output over an input voltage range that spans (i.e., can be higher or lower than) the output. Recommended component placement for an SO-8 package SEPIC is shown in Figure 9.

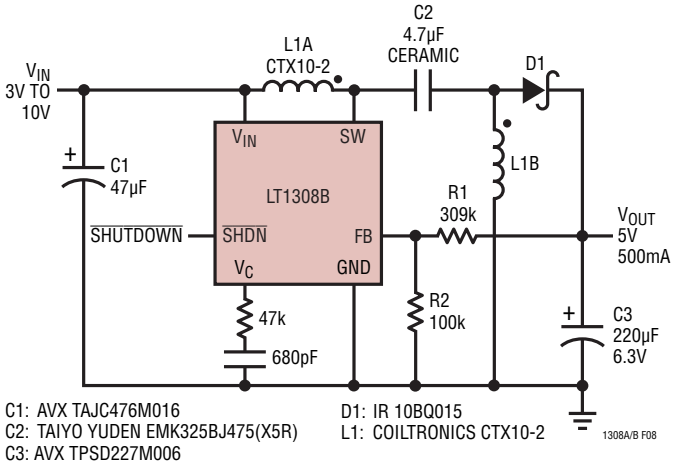


Figure 8. SEPIC (Single-Ended Primary Inductance Converter) Converts 3V to 10V Input to a 5V/500mA Regulated Output

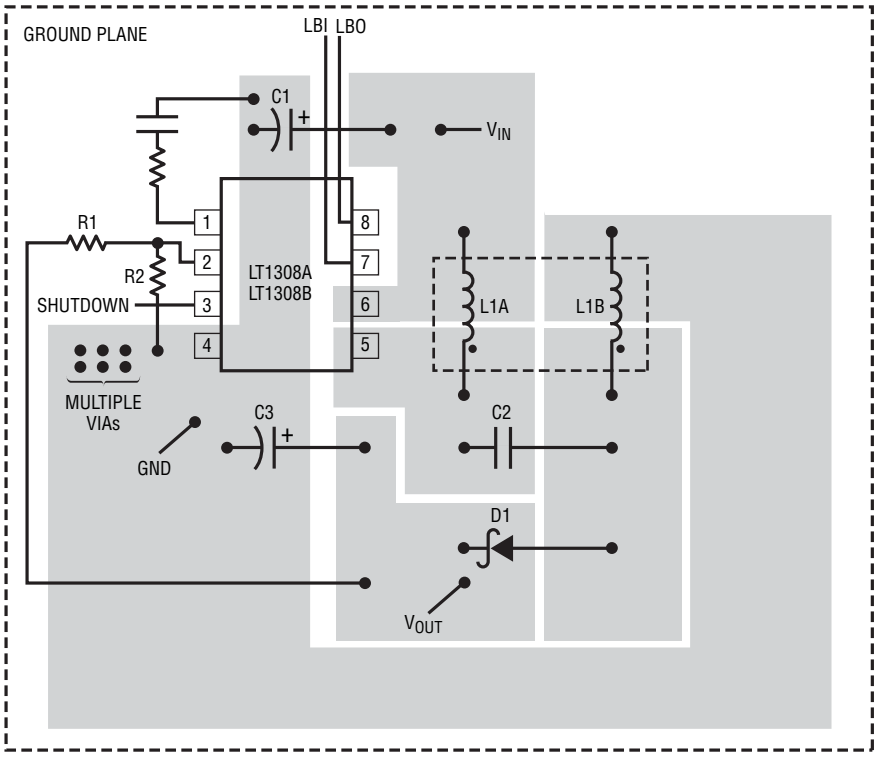


Figure 9. Recommended Component Placement for SEPIC

APPLICATIONS INFORMATION

$\overline{SHDN}$ PIN

The LT1308A/LT1308B $\overline{SHDN}$ pin is improved over the LT1308. The pin does not require tying to V_{IN} to enable the device, but needs only a logic level signal. The voltage on the $\overline{SHDN}$ pin can vary from 1V to 10V independent of V_{IN}. Further, floating this pin has the same effect as grounding, which is to shut the device down, reducing current drain to 1µA or less.

LOW-BATTERY DETECTOR

The low-battery detector on the LT1308A/LT1308B features improved accuracy and drive capability compared to the LT1308. The 200mV reference has an accuracy of ±2% and the open-collector output can sink 50µA. The LT1308A/LT1308B low-battery detector is a simple PNP input gain stage with an open-collector NPN output. The negative input of the gain stage is tied internally to a 200mV reference. The positive input is the LBI pin. Arrangement as a low-battery detector is straightforward. Figure 10 details hookup. R1 and R2 need only be low enough in value so that the bias current of the LBI pin doesn't cause large errors. For R2, 100k is adequate. The 200mV reference can also be accessed as shown in Figure 11.

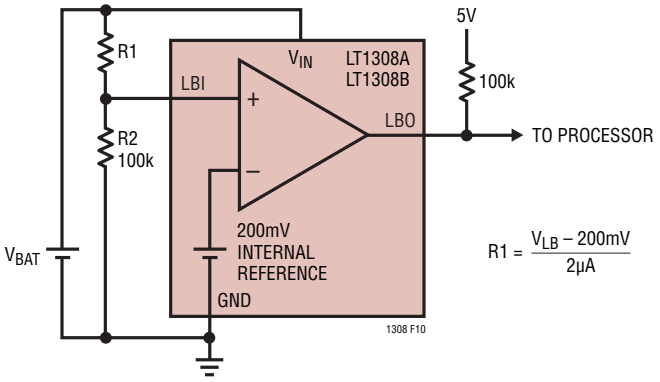


Figure 10. Setting Low-Battery Detector Trip Point

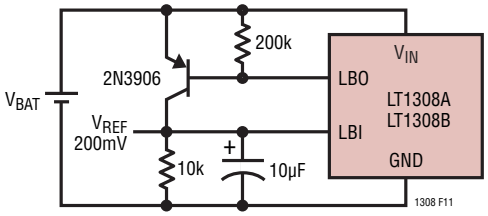


Figure 11. Accessing 200mV Reference

A cross plot of the low-battery detector is shown in Figure 12. The LBI pin is swept with an input which varies from 195mV to 205mV, and LBO (with a 100k pull-up resistor) is displayed.

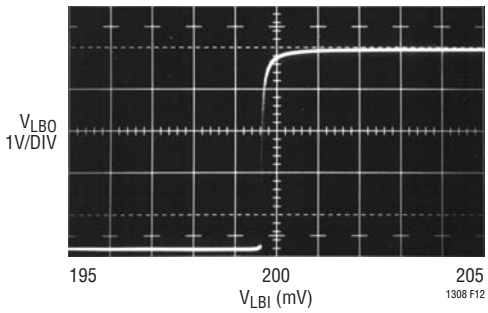


Figure 12. Low-Battery Detector Input/Output Characteristic

START-UP

The LT1308A/LT1308B can start up into heavy loads, unlike many CMOS DC/DC converters that derive operating voltage from the output (a technique known as "bootstrapping"). Figure 13 details start-up waveforms of Figure 1's circuit with a 20Ω load and V_{IN} of 1.5V. Inductor current rises to 3.5A as the output capacitor is charged. After the output reaches 5V, inductor current is about 1A. In Figure 14, the load is 5Ω and input voltage is 3V. Output voltage reaches 5V in 500µs after the device is enabled. Figure 15 shows start-up behavior of Figure 5's SEPIC circuit, driven from a 9V input with a 10Ω load. The output reaches 5V in about 1ms after the device is enabled.

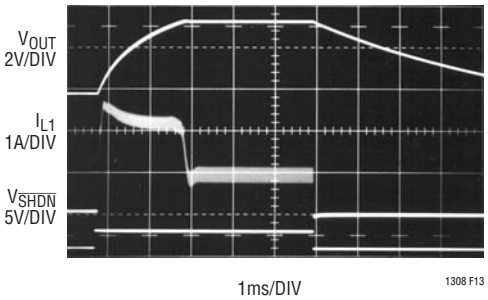


Figure 13. 5V Boost Converter of Figure 1. Start-Up from 1.5V Input into 20Ω Load

APPLICATIONS INFORMATION

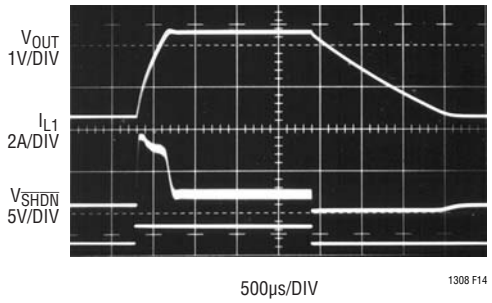


Figure 14. 5V Boost Converter of Figure 1. Start-Up from 3V Input into 5Ω Load

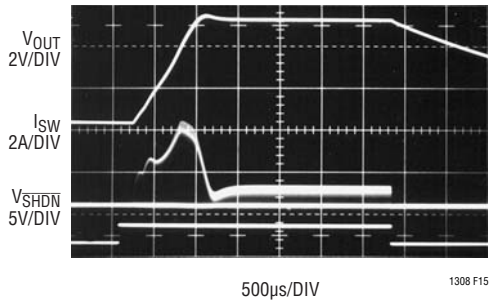


Figure 15. 5V SEPIC Start-Up from 9V Input into 10Ω Load

Soft-Start

In some cases it may be undesirable for the LT1308A/LT1308B to operate at current limit during start-up, e.g., when operating from a battery composed of alkaline cells. The inrush current may cause sufficiency internal voltage drop to trigger a low-battery indicator. A programmable soft-start can be implemented with 4 discrete components. A 5V to 12V boost converter using the LT1308B is detailed in Figure 16. C4 differentiates V_{OUT}, causing a current to flow into R3 as V_{OUT} increases. When this current exceeds 0.7V/33k, or 21µA, current flows into the base of Q1. Q1's collector then pulls current out the V_C pin, creating a feedback loop where the slope of V_{OUT} is limited as follows:

$$\frac{\Delta V_{OUT}}{\Delta t} = \frac{0.7V}{33k \bullet C4}$$

With C4 = 33nF, V_{OUT}/t is limited to 640mV/ms. Start-up waveforms for Figure 16's circuit are pictured in Figure 17. Without the soft-start circuit implemented, the inrush current reaches 3A. The circuit reaches final output voltage in approximately 250µs. Adding the soft-start components reduces inductor current to less than 1A, as detailed in Figure 18, while the time required to reach final output voltage increases to about 15ms. C4 can be adjusted to achieve any output slew rate desired.

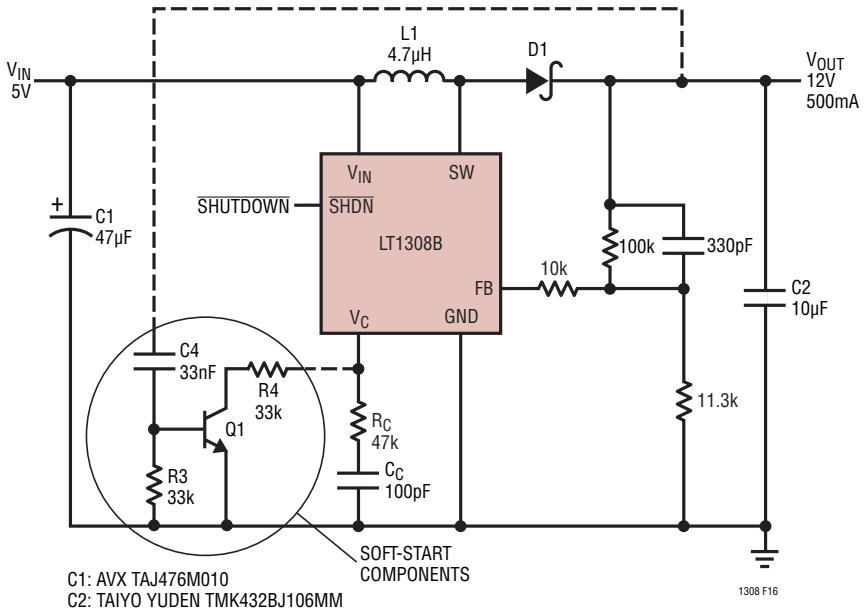


Figure 16. 5V to 12V Boost Converter with Soft-Start Components Q1, C4, R3 and R4

APPLICATIONS INFORMATION

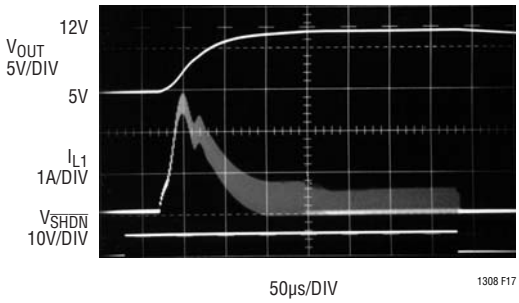


Figure 17. Start-Up Waveforms of Figure 16's Circuit without Soft-Start Components

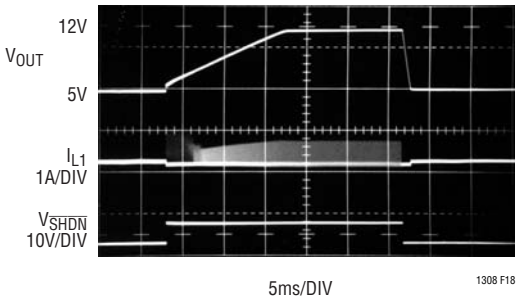


Figure 18. Start-Up Waveforms of Figure 16's Circuit with Soft-Start Components Added

COMPONENT SELECTION

Diodes

We have found ON Semiconductor MBRS130 and International Rectifier 10BQ015 to perform well. For applications where V_{OUT} exceeds 30V, use 40V diodes such as MBRS140 or 10BQ040.

Height limited applications may benefit from the use of the MBRM120. This component is only 1mm tall and offers performance similar to the MBRS130.

Inductors

Suitable inductors for use with the LT1308A/LT1308B must fulfill two requirements. First, the inductor must be able to handle current of 2A steady-state, as well as support transient and start-up current over 3A without inductance decreasing by more than 50% to 60%. Second, the DCR of the inductor should have low DCR, under 0.05Ω so that copper loss is minimized. Acceptable inductance values range between 2µH and 20µH, with 4.7µH best for most applications. Lower value inductors are physically smaller than higher value inductors for the same current capability.

Table 1 lists some inductors we have found to perform well in LT1308A/LT1308B application circuits. This is not an exclusive list.

Table 1

VENDOR	PART NO.	VALUE	PHONE NO.
Murata	LQH6C4R7	4.7µH	770-436-1300
Sumida	CDRH734R7	4.7µH	847-956-0666
Coiltronics	CTX5-1	5µH	561-241-7876
Coilcraft	LPO2506IB-472	4.7µH	847-639-6400

Capacitors

Equivalent Series Resistance (ESR) is the main issue regarding selection of capacitors, especially the output capacitors.

The output capacitors specified for use with the LT1308A/LT1308B circuits have low ESR and are specifically designed for power supply applications. Output voltage ripple of a boost converter is equal to ESR multiplied by switch current. The performance of the AVX TPSD227M006 220µF tantalum can be evaluated by referring to Figure 3. When the load is 800mA, the peak switch current is approximately 2A. Output voltage ripple is about $60mV_{P-P}$, so the ESR of the output capacitor is 60mV/2A or 0.03Ω. Ripple can be further reduced by paralleling ceramic units.

Table 2 lists some capacitors we have found to perform well in the LT1308A/LT1308B application circuits. This is not an exclusive list.

Table 2

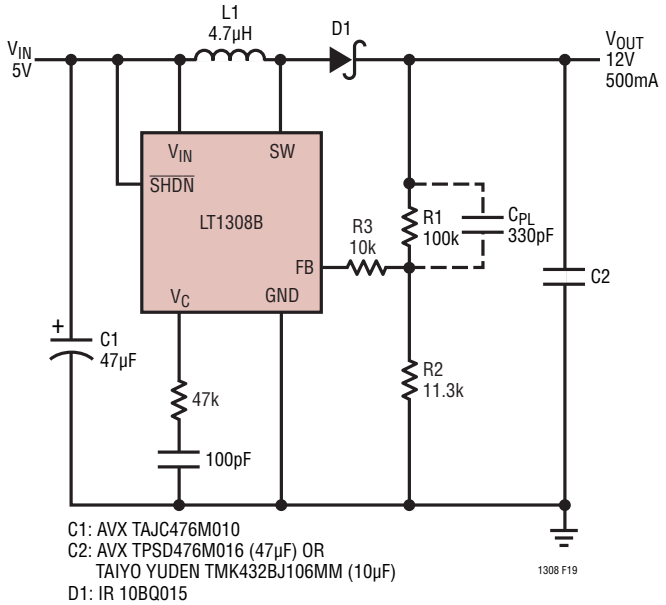
VENDOR	SERIES	PART NO.	VALUE	PHONE NO.
AVX	TPS	TPSD227M006	220µF, 6V	803-448-9411
AVX	TPS	TPSD107M010	100µF, 10V	803-448-9411
Taiyo Yuden	X5R	LMK432BJ226	22µF, 10V	408-573-4150
Taiyo Yuden	X5R	TMK432BJ106	10µF, 25V	408-573-4150

APPLICATIONS INFORMATION

Ceramic Capacitors

Multilayer ceramic capacitors have become popular, due to their small size, low cost, and near-zero ESR. Ceramic capacitors can be used successfully in LT1308A/LT1308B designs provided loop stability is considered. A tantalum capacitor has some ESR and this causes an "ESR zero" in the regulator loop. This zero is beneficial to loop stability. Ceramics do not have appreciable ESR, so the zero is lost when they are used. However, the LT1308A/LT1308B have external compensation pin (V_C) so component values can be adjusted to achieve stability. A phase lead capacitor can also be used to tune up load step response to optimum levels, as detailed in the following paragraphs.

Figure 19 details a 5V to 12V boost converter using either a tantalum or ceramic capacitor for C2. The input capacitor has little effect on loop stability, as long as minimum capacitance requirements are met. The phase lead capacitor C_{PL} parallels feedback resistor R1. Figure 20 shows load step response of a 50mA to 500mA load step using a 47µF tantalum capacitor at the output. Without the phase lead capacitor, there is some ringing, suggesting the phase margin is low. C_{PL} is then added, and response to the same load step is pictured in Figure 21. Some phase margin is restored, improving the response. Next, C2 is replaced by a 10µF, X5R dielectric, ceramic capacitor.



C1: AVX TAJC476M010
C2: AVX TPSD476M016 (47µF) OR
TAIYO YUDEN TMK432BJ106MM (10µF)
D1: IR 10BQ015
L1: MURATA LQH6C4R7

Figure 19. 5V to 12V Boost Converter

Without C_{PL}, load step response is pictured in Figure 22. Although the output settles faster than the tantalum case, there is appreciable ringing, again suggesting phase margin is low. Figure 23 depicts load step response using the 10µF ceramic output capacitor and C_{PL}. Response is clean and no ringing is evident. Ceramic capacitors have the added benefit of lowering ripple at the switching frequency due to their very low ESR. By applying C_{PL} in tandem with the series RC at the V_C pin, loop response can be tailored to optimize response using ceramic output capacitors.

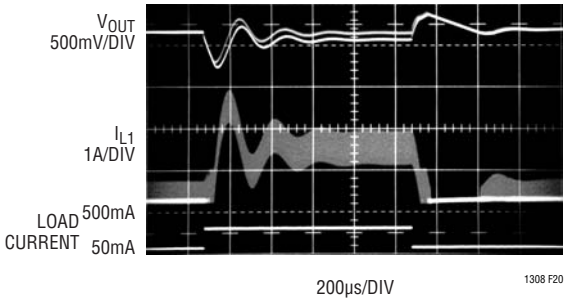


Figure 20. Load Step Response of LT1308B 5V to 12V Boost Converter with 47µF Tantalum Output Capacitor

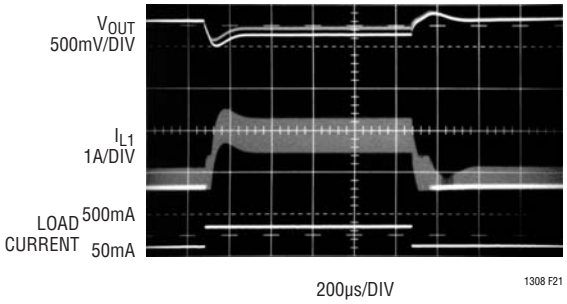


Figure 21. Load Step Response with 47µF Tantalum Output Capacitor and Phase Lead Capacitor C_{PL}

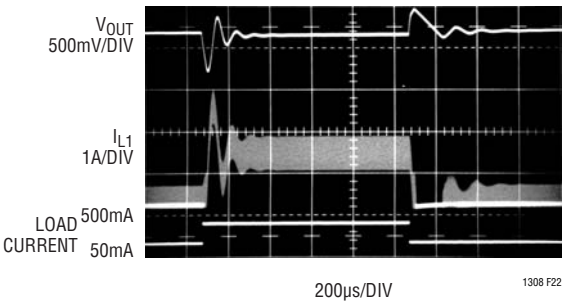


Figure 22. Load Step Response with 10µF X5R Ceramic Output Capacitor

APPLICATIONS INFORMATION

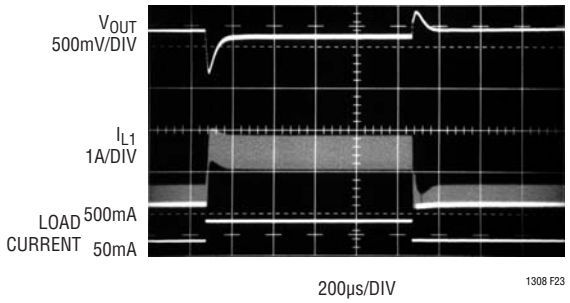


Figure 23. Load Step Response with 10µF X5R Ceramic Output Capacitor and C_{PL}

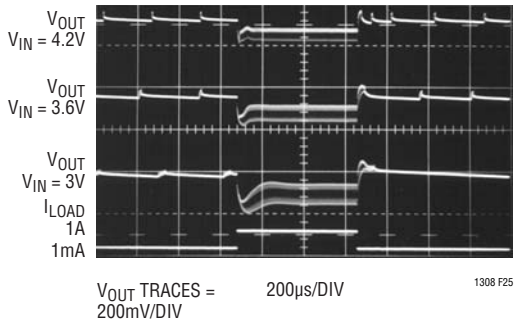


Figure 25. LT1308A Li-Ion to 5V Boost Converter Transient Response to 1A Load Step

GSM AND CDMA PHONES

The LT1308A/LT1308B are suitable for converting a single Li-Ion cell to 5V for powering RF power stages in GSM or CDMA phones. Improvements in the LT1308A/LT1308B error amplifiers allow external compensation values to be reduced, resulting in faster transient response compared to the LT1308. The circuit of Figure 24 (same as Figure 1, printed again for convenience) provides a 5V, 1A output from a Li-Ion cell. Figure 25 details transient response at the LT1308A operating at a V_{IN} of 4.2V, 3.6V and 3V. Ripple voltage in Burst Mode operation can be seen at 10mA load. Figure 26 shows transient response of the LT1308B under the same conditions. Note the lack of Burst Mode ripple at 10mA load.

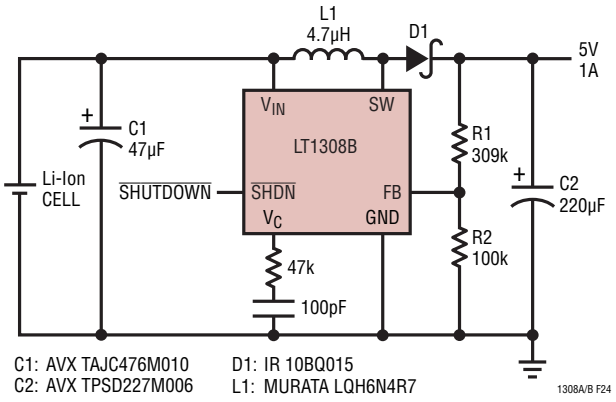


Figure 24. Li-Ion to 5V Boost Converter Delivers 1A

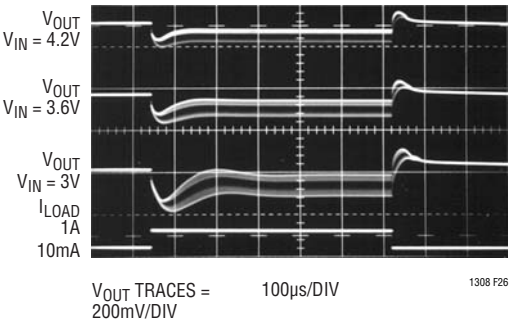
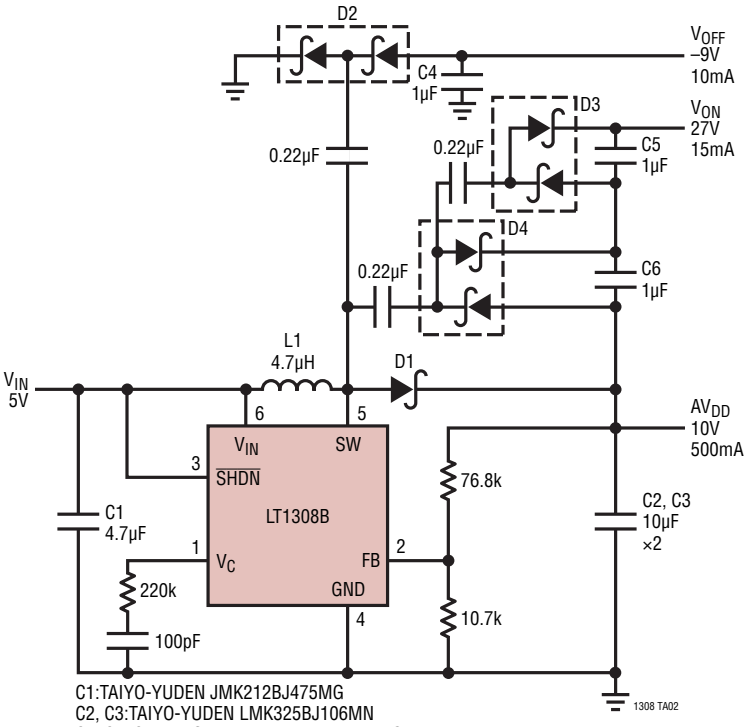


Figure 26. LT1308B Li-Ion to 5V Boost Converter Transient Response to 1A Load Step

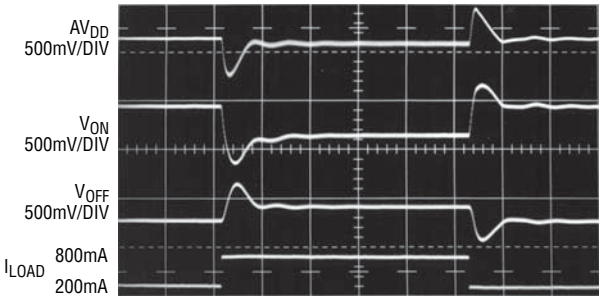
TYPICAL APPLICATIONS

Triple Output TFTLCD Bias Supply



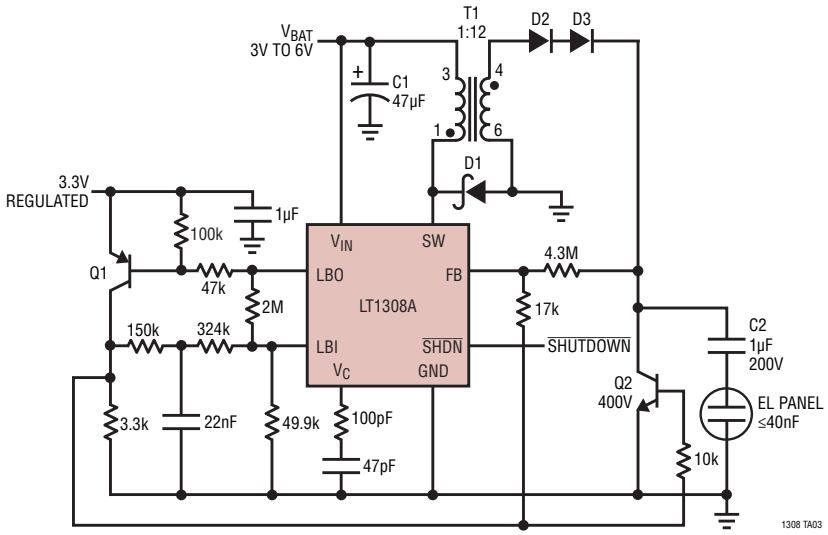
C1:TAIYO-YUDEN JMK212BJ475MG
C2, C3:TAIYO-YUDEN LMK325BJ106MN
C4, C5, C6:TAIYO-YUDEN EMK212BJ105MG
D1: MBRM120
D2,D3,D4: BAT54S
L1: TOKO 817FY-4R7M

TFTLCD Bias Supply Transient Response



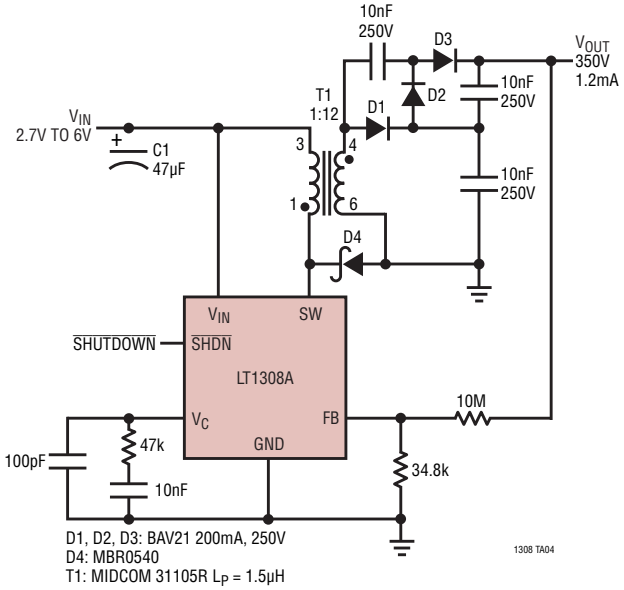
TYPICAL APPLICATIONS

40nF EL Panel Driver



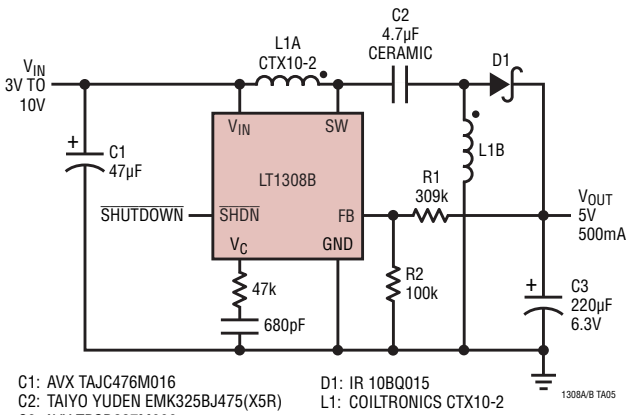
C1: AVX TAJC476M010
C2: VITRAMON VJ225Y105KXCAT
D1: BAT54
D2, D3: BAV21
Q1: MMBT3906
Q2: ZETEX FCX458
T1: MIDCOM 31105

High Voltage Supply 350V at 1.2mA



D1, D2, D3: BAV21 200mA, 250V
D4: MBR0540
T1: MIDCOM 31105R L_P = 1.5µH

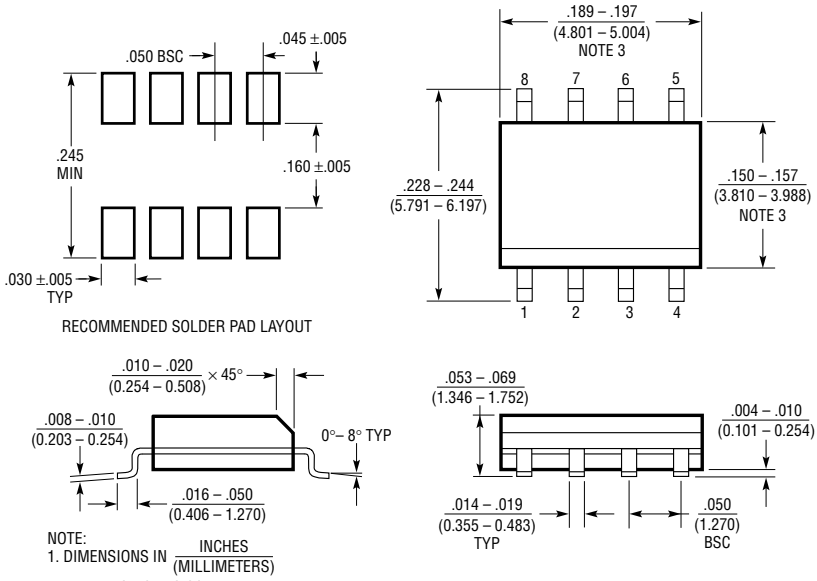
SEPIC Converts 3V to 10V Input to a 5V/500mA Regulated Output



C1: AVX TAJC476M016
C2: TAIYO YUDEN EMK325BJ475(X5R)
C3: AVX TPSD227M006
D1: IR 10BQ015
L1: COILTRONICS CTX10-2

PACKAGE DESCRIPTION

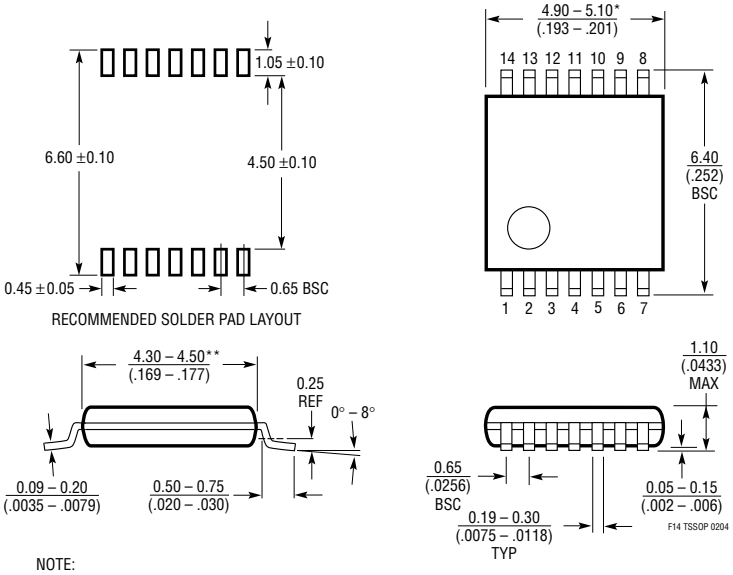
S8 Package
8-Lead Plastic Small Outline (Narrow .150 Inch)
(Reference LTC DWG # 05-08-1610)



NOTE:
1. DIMENSIONS IN $\frac{\text{INCHES}}{(\text{MILLIMETERS})}$
2. DRAWING NOT TO SCALE
3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006" (0.15mm)

SO8 0303

F Package
14-Lead Plastic TSSOP (4.4mm)
(Reference LTC DWG # 05-08-1650)



NOTE:
1. CONTROLLING DIMENSION: MILLIMETERS
2. DIMENSIONS ARE IN $\frac{\text{MILLIMETERS}}{(\text{INCHES})}$
3. DRAWING NOT TO SCALE
*DIMENSIONS DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .152mm (.006") PER SIDE
**DIMENSIONS DO NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED .254mm (.010") PER SIDE

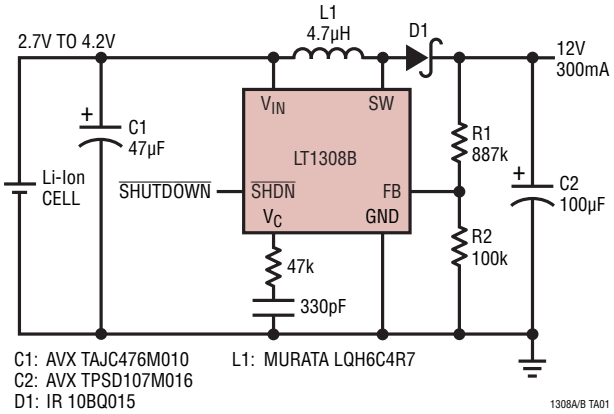
REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
B	12/10	Obsoleted F Package	2

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATION

Li-Ion to 12V/300mA Step-Up DC/DC Converter



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1302	High Output Current Micropower DC/DC Converter	5V/600mA from 2V, 2A Internal Switch, 200µA I_Q
LT1304	2-Cell Micropower DC/DC Converter	5V/200mA, Low-Battery Detector Active in Shutdown
LT1307/LT1307B	Single Cell, Micropower, 600kHz PWM DC/DC Converters	3.3V at 75mA from One Cell, MSOP Package
LT1316	Burst Mode Operation DC/DC with Programmable Current Limit	1.5V Minimum, Precise Control of Peak Current Limit
LT1317/LT1317B	Micropower, 600kHz PWM DC/DC Converters	100µA I_Q, Operate with V_{IN} as Low as 1.5V
LTC®1474	Micropower Step-Down DC/DC Converter	94% Efficiency, 10µA I_Q, 9V to 5V at 250mA
LTC1516	2-Cell to 5V Regulated Charge Pump	12µA I_Q, No Inudctors, 5V at 50mA from 3V Input
LTC1522	Micropower, 5V Charge Pump DC/DC Converter	Regulated 5V ±4% Output, 20mA from 3V Input
LT1610	Single-Cell Micropower DC/DC Converter	3V at 30mA from 1V, 1.7MHz Fixed Frequency
LT1611	Inverting 1.4MHz Switching Regulator in 5-Lead SOT-23	–5V at 150mA from 5V Input, Tiny SOT-23 package
LT1613	1.4MHz Switching Regulator in 5-Lead SOT-23	5V at 200mA from 4.4V Input, Tiny SOT-23 package
LT1615	Micropower Step-Up DC/DC in 5-Lead SOT-23	20µA I_Q, 36V, 350mA Switch
LT1617	Micropower Inverting DC/DC Converter in SOT-23	V_{IN} = 1V to 15V; V_{OUT} to –34V
LTC1682	Doubler Charge Pump with Low Noise LDO	Adjustable or Fixed 3.3V, 5V Outputs, 60µV_{RMS} Output Noise
LT1949	600kHz, 1A Switch PWM DC/DC Converter	1.1A, 0.5Ω, 30V Internal Switch, V_{IN} as Low as 1.5V
LT1949-1	1.1MHz, 1A Switch DC/DC Converter	1.1MHz Version of LT1949

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